



勝特力材料 886-3-5753170
胜特力电子(上海) 86-21-34970699
胜特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

STPS60150C

POWER SCHOTTKY RECTIFIER

Table 1: Main Product Characteristics

$I_{F(AV)}$	2 x 30 A
V_{RRM}	150 V
T_j	175°C
$V_F(\text{max})$	0.76 V

FEATURES AND BENEFITS

- High junction temperature capability
- Low leakage current
- Low thermal resistance
- High frequency operation
- Avalanche specification

DESCRIPTION

Dual center tab Schottky rectifier suited for High Frequency server and telecom base station SMPS. Packaged in TO-220AB, this device combines high current rating and low volume to enhance both reliability and power density of the application.

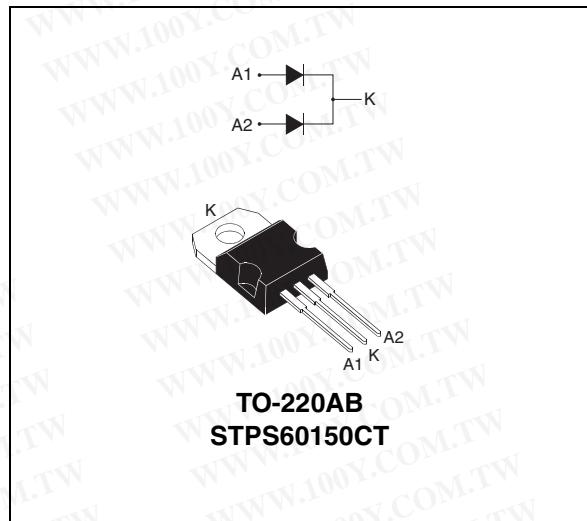


Table 2: Order Codes

Part Number	Marking
STPS60150CT	STPS60150CT

Table 3: Absolute Ratings (limiting values, per diode)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage			150	V
$I_{F(\text{RMS})}$	RMS forward voltage			60	A
$I_{F(AV)}$	Average forward current	$T_c = 150^\circ\text{C}$	Per diode	30	A
		$\delta = 0.5$	Per device	60	
I_{FSM}	Surge non repetitive forward current	tp = 10ms sinusoidal		270	A
P_{ARM}	Repetitive peak avalanche power	tp = 1μs $T_j = 25^\circ\text{C}$		17300	W
T_{stg}	Storage temperature range			-65 to + 175	°C
T_j	Maximum operating junction temperature *			175	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/μs

* : $\frac{dP_{tot}}{dT_j} > \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

STPS60150C

Table 4: Thermal Parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	Per diode Total	°C/W
R _{th(c)}	Coupling	0.4	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{\text{th(j-c)}} (\text{Per diode}) + P(\text{diode 2}) \times R_{\text{th(c)}}$$

Table 5: Static Electrical Characteristics (per diode)

Symbol	Parameter	Tests conditions	Min.	Typ	Max.	Unit	
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}		3	15	µA
		T _j = 125°C			3	10	mA
V _F **	Forward voltage drop	T _j = 25°C	I _F = 30A		0.94	V	
		T _j = 125°C	I _F = 30A		0.72		
		T _j = 25°C	I _F = 60A		0.97		
		T _j = 125°C	I _F = 60A		0.86		

Pulse test: * tp = 5 ms, δ < 2%

** tp = 380 µs, δ < 2%

To evaluate the conduction losses use the following equation: P = 0.6 × I_{F(AV)} + 0.0053 I_F² (RMS)

勝特力材料 886-3-5753170
 胜特力电子(上海) 86-21-34970699
 胜特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

Figure 1: Average forward power dissipation versus average forward current (per diode)

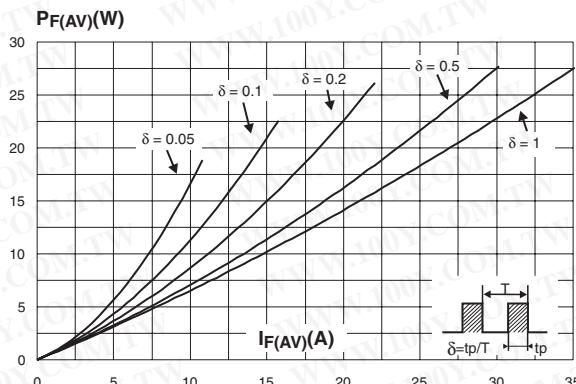


Figure 3: Normalized avalanche power derating versus pulse duration

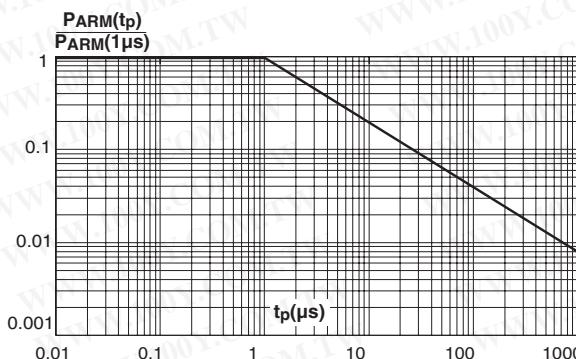


Figure 5: Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

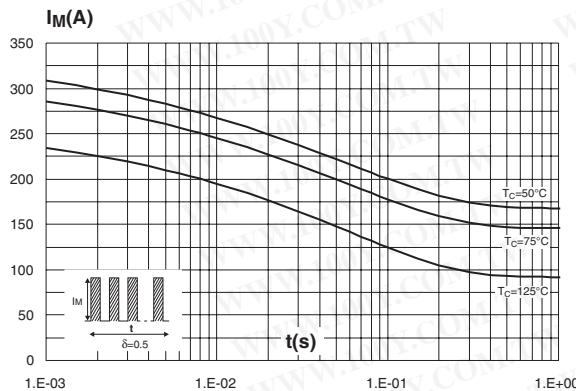


Figure 2: Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

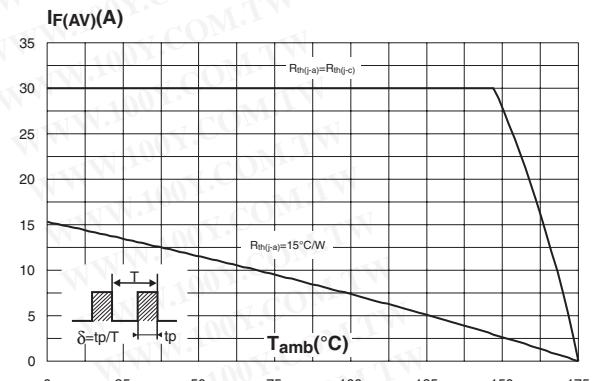


Figure 4: Normalized avalanche power derating versus junction temperature

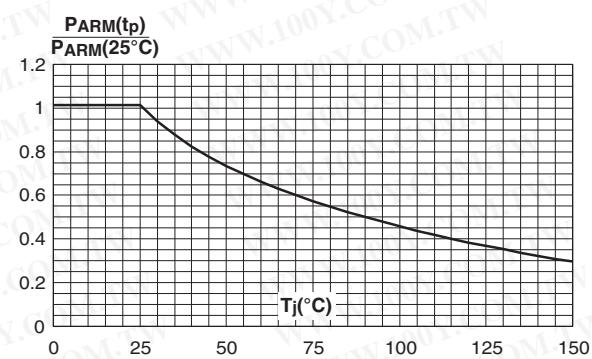
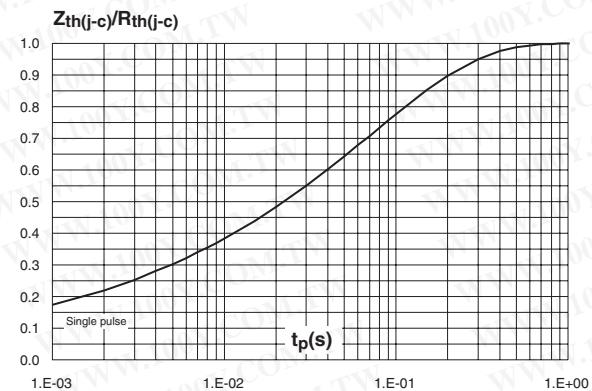


Figure 6: Relative variation of thermal impedance junction to case versus pulse duration (per diode)



STPS60150C

Figure 7: Reverse leakage current versus reverse voltage applied (typical values, per diode)

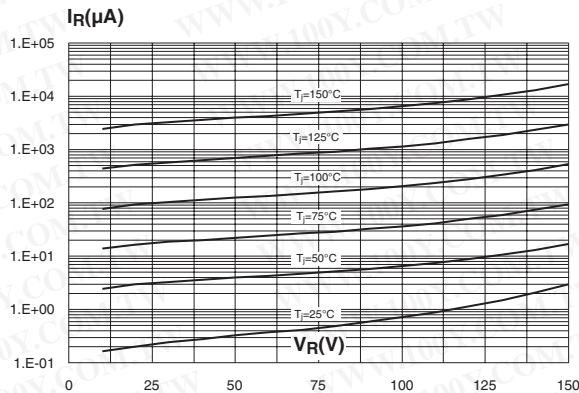


Figure 8: Junction capacitance versus reverse voltage applied (typical values, per diode)

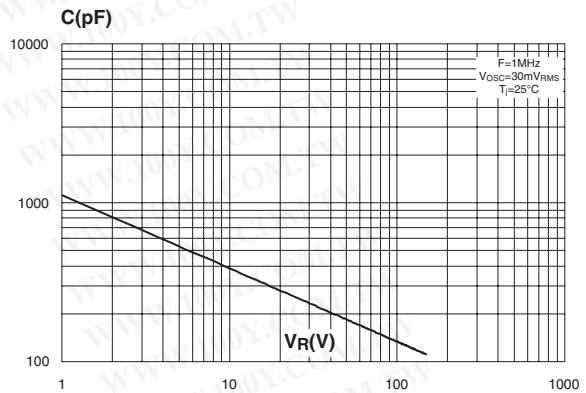
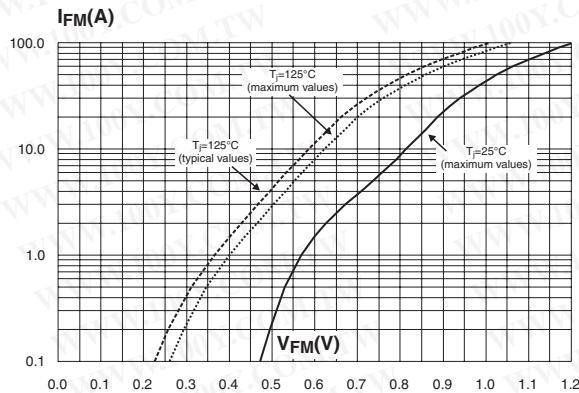


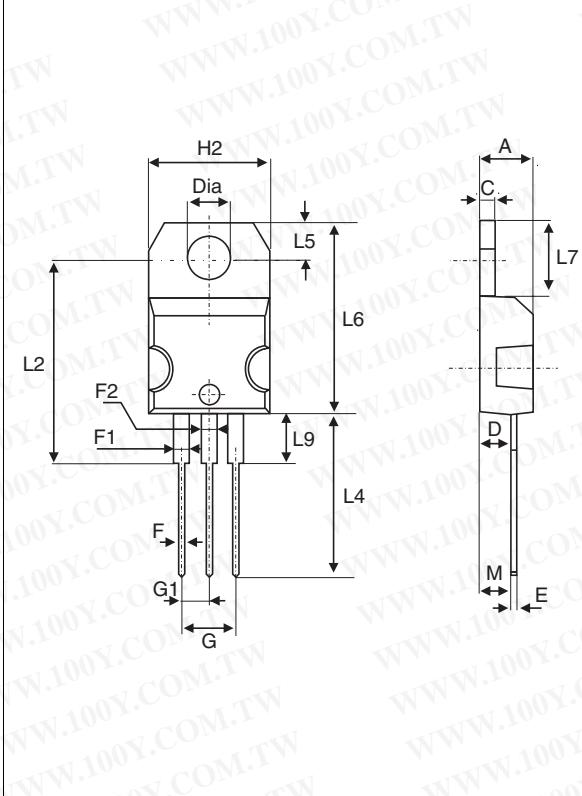
Figure 9: Forward voltage drop versus forward current (per diode)



勝特力材料 886-3-5753170
胜特力电子(上海) 86-21-34970699
胜特力电子(深圳) 86-755-83298787

[Http://www.100y.com.tw](http://www.100y.com.tw)

Figure 10: TO-220AB Package Mechanical Data



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

Table 6: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS60150CT	STPS60150CT	TO-220AB	2.20 g	50	Tube

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1.0 m.N.

Table 7: Revision History

Date	Revision	Description of Changes
19-Oct-2004	1	First issue.

勝特力材料 886-3-5753170
胜特力电子(上海) 86-21-34970699
胜特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics.
All other names are the property of their respective owners

© 2004 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America
www.st.com